## Magnetic domains in ultrathin cobalt films

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Technology of ultrathin film preparation gives new opportunities for tuning samples magnetic properties [1] especially magnetic anisotropy characterized by the quality factor, Q. Such nanostructures opened *new* area for magnetization distribution studies. Review of magnetic domain structure (**DS**) investigations in Co nanostructures is presented. In a typical ultrathin film, with perpendicular anisotropy, DS sizes are large and DS geometry peculiarities can be described by a model of a patchy inhomogeneous media with realistic distribution of local coercivities, neglecting magnetostatic forces [2]. Drastic DS size decrease was observed while approaching the reorientation phase transition from perpendicular to in-plane magnetization, driven by either magnetic anisotropy decrease or in-plane applied magnetic field [3,4]. Combined both analytical study and numerical simulations were performed for description of magnetization distribution. For stripe-like DS the minimal period  $p_{min}/d$  is a function of  $l_{ex}/d$  (where  $l_{ex}$  is the exchange length, d - film thickness). A minimal  $8\pi l_{ex}$  DS period is predicted. Micromagnetic simulations [5] are based on real magnetic material parameters [1].

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<sup>[1]</sup> M. Kisielewski et al., Phys. Rev. Lett. 89, 8, 87203 (2002) and references therein.

<sup>[2]</sup> J. Ferre Phys. et al., Phys.Rev.B, 55, 22, 15 092 (1997).

<sup>[3]</sup> M. Speckmann, H.P. Oepen, and H. Ibach, Phys. Rev. Lett. 75, 2035 (1995).

<sup>[4]</sup> M. Kisielewski et al., J. Appl. Phys. 93, 10, 6966 (2003).

<sup>[5]</sup> M. Kisielewski et al., Phys.Rev.B to be published.